


	<h2 style="color: red;">SUD19P06-60L-E3</h2>
	<p><b>Hersteller-Teilenummer:</b> SUD19P06-60L-E3</p> <p><b>Hersteller / Marke:</b> Vishay / Siliconix</p> <p><b>Teil der Beschreibung:</b> MOSFET P-CH 60V 19A TO252</p> <p><b>Datenblätter:</b>  <a href="#">SUD19P06-60L-E3.pdf</a></p> <p><b>RoHs Status:</b> Bleifrei / RoHS-konform</p> <p><b>Lagerzustand:</b> New original, 45615 pcs Stock Available.</p> <p><b>Liefern von:</b> Hong Kong</p> <p><b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

### Spezifikationen

Teilenummer	SUD19P06-60L-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET P-CH 60V 19A TO252
Kategorie	<a href="#">Diskrete Halbleiterprodukte &gt; Transistoren-FETs,</a>
Teilstatus	45615 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	2.7W (Ta), 46W (Tc)
Typ FET	P-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	19A (Tc)
Rds On (Max) @ Id, Vgs	60 mOhm @ 10A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	40nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1710pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Tape & Reel (TR)

SUD19P06-60L-E3 ist neu im Original, Suche SUD19P06-60L-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD19P06-60L-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SUD19P06-60L-E3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SUD19P06-60L-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 60V 19A TO252</p>	 <p><b>SUD19P06-60-E3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 60V 18.3A TO252</p>	 <p><b>SUD20N10-66L-T1-GE3</b> V SUD20N10-66L-T1-GE3 V</p>	 <p><b>SUD20N10-66L-GE3</b> Vishay / Siliconix MOSFET N-CH 100V 16.9A TO-252</p>
 <p><b>SUD20N10-66L-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 100V 16.9A TO-252</p>	 <p><b>SUD20N03</b> S SUD20N03 S</p>	 <p><b>SUD19P06-60-GE3</b> Vishay / Siliconix MOSFET P-CH 60V 18.3A TO-252</p>	 <p><b>SUD19P06-60-GE3</b> Electro-Films (EFI) / Vishay MOSFET P-CH 60V 18.3A TO-252</p>

### heiße Teile

Mehr

⊛ SUD15N15-95	↔ SUD15N15-95-E3	➔ SUD15N15-95-E3	D SUD15P01-52-E3	➔ SUD17N25-165
⊣ SUD17N25-165-E3	⊛ SUD17N25-165-E3	D SUD17N25-165-T1-E3	➔ SUD17N25-165-T4-E3	➔ SUD19N20
⊛ SUD19N20-90	⊣ SUD19N20-90-E2	⊛ SUD19N20-90-E3	↔ SUD19N20-90-E3	➔ SUD19N20-90-T4-E3
D SUD19N20-90-T4-E3	⊛ SUD19P06	⊣ SUD19P06-155L	⊛ SUD19P06-60	➔ SUD19P06-60-E3
➔ SUD19P06-60-E3	↔ SUD19P06-60-GE3	⊛ SUD19P06-60-GE3	⊣ SUD19P06-60L	➔ SUD19P06-60L-E3
↔ SUD20N03	➔ SUD20N10-66L	D SUD20N10-66L-GE3	⊛ SUD20N10-66L-GE3	⊣ SUD20N10-66L-T1-GE3
⊛ SUD20P15-306	D SUD23N06-31	➔ SUD23N06-31-E3	↔ SUD23N06-31-GE3	➔ SUD23N06-31-GE3
⊣ SUD23N06-31L	⊛ SUD23N06-31L-E3	↔ SUD23N06-31L-E3	➔ SUD23N06-31L-GE3	➔ SUD23N06-31L-T1-E3
⊛ SUD23N06-31_08	⊣ SUD23N06-31_11	⊛ SUD25N04-25	D SUD25N04-25-T4-E3	➔ SUD25N04-25-T4-E3
↔ SUD25N05-13L	⊛ SUD25N05-45L	⊣ SUD25N06-45L	⊛ SUD25N06-45L-E3	➔ SUD25N06-45L-GE3

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